

High Speed Infrared Emitting Diodes, 940 nm, **Surface Emitter Technology**



DESCRIPTION

As part of the SurfLightTM portfolio, the VSMY14940 is an infrared, 940 nm, side looking emitting diode based on GaAlAs surface emitter chip technology with extreme high radiant intensities, high optical power and high speed, molded in clear, untinted PCB based package (with lens) for surface mounting (SMD).

APPLICATIONS

- Emitter for remote control (38 kHz)
- · Learning remote control
- · Optical switch

FEATURES

· Package type: surface-mount

· Package form: side view

• Dimensions (L x W x H in mm): 3.0 x 2.51 x 1.2

Peak wavelength: λ_p = 940 nm

· High reliability

High radiant power

· Very high radiant intensity

• Angle of half intensity: $\varphi = \pm 9^{\circ}$

· Suitable for high pulse current operation

• Floor life: 168 h, MSL 3, according to J-STD-020

· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912









Photointerrupters

PRODUCT SUMMARY				
COMPONENT	I _e (mW/sr)	φ (deg)	$λ_p$ (nm)	t _r (ns)
VSMY14940	90	± 9	940	5

· Test condition see table "Basic Characteristics"

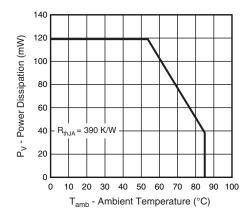
ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
VSMY14940	Tape and reel	MOQ: 1500 pcs, 1500 pcs/reel	Side view	

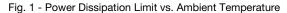
Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_{R}	5	V
Forward current		I _F	70	mA
Surge forward current	t _p = 100 μs	I _{FSM}	0.7	Α
Power dissipation		P_V	119	mW
Junction temperature		Tj	100	°C
Operating temperature range		T _{amb}	-40 to +85	°C
Storage temperature range		T _{stg}	-55 to +100	°C
Soldering temperature	According to Fig. 10, J-STD-020	T_{sd}	260	°C
Thermal resistance junction-to-ambient	J-STD-051, soldered on PCB	R_{thJA}	390	K/W







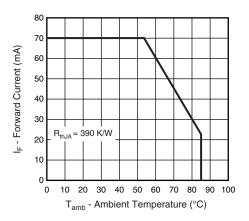


Fig. 2 - Forward Current Limit vs. Ambient Temperature

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	1.1	1.3	1.5	V
	$I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	V _F	-	1.5	-	V
	$I_F = 0.7 \text{ A}, t_p = 100 \mu \text{s}$	V _F	-	3.0	-	V
Temperature coefficient of V _F	I _F = 20 mA	TK _{VF}	-	-0.9	-	mV/K
Reverse current		I _R	Not designed for reverse operation			nA
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ	-	30	-	pF
Radiant intensity	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	l _e	15	25	-	mW/sr
	$I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	l _e	-	90	-	mW/sr
	$I_F = 0.7 \text{ A}, t_p = 100 \mu \text{s}$	l _e	-	560	-	mW/sr
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}, \ V_R = 5 \text{ V}$	I _{ra}	-	0.5	-	μΑ
Radiant power	$I_F = 70 \text{ mA}, t_p = 20 \text{ ms}$	фe	-	40	_	mW
Temperature coefficient of radiant power	I _F = 70 mA	ΤΚφ _e	-	-0.21	-	%/K
Angle of half intensity		φ	-	± 9	-	deg
Peak wavelength	I _F = 70 mA	λ_{p}	920	940	960	nm
Spectral bandwidth	I _F = 70 mA	Δλ	-	55	-	nm
Temperature coefficient of λ_p	I _F = 70 mA	TKλ _p	-	0.28	-	nm/K
Rise time	I _F = 70 mA, 10 % to 90 %	t _r	-	5	-	ns
Fall time	I _F = 70 mA, 10 % to 90 %	t _f	-	6	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

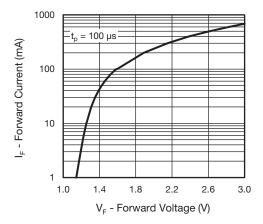


Fig. 3 - Forward Current vs. Forward Voltage

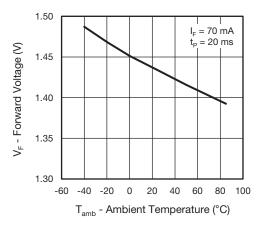


Fig. 4 - Forward Voltage vs. Ambient Temperature

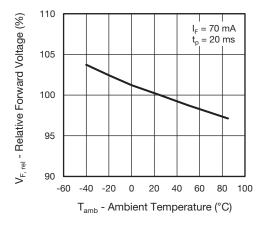


Fig. 5 - Relative Forward Voltage vs. Ambient Temperature

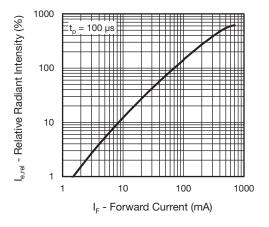


Fig. 6 - Relative Radiant Intensity vs. Forward Current

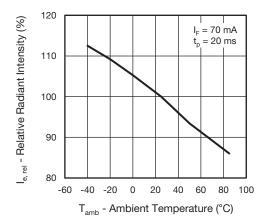


Fig. 7 - Relative Radiant Intensity vs. Ambient Temperature

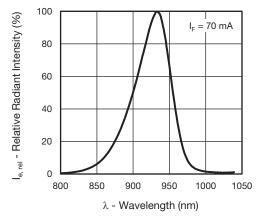


Fig. 8 - Relative Radiant Intensity vs. Wavelength



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0° 10° 20° 30° rel - Relative Radiant Intensity Angular Displacement 40° 1.0 0.9 50° 8.0 60° 70° 0.7 80° 0.6 0.4 0.2 0

Fig. 9 - Relative Radiant Intensity vs. Angular Displacement

SOLDER PROFILE

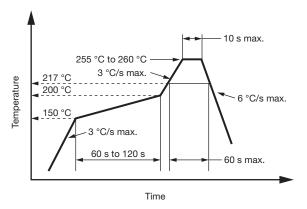


Fig. 10 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

Vishay Semiconductors

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 168 h

Conditions: T_{amb} < 30 °C, RH < 60 %

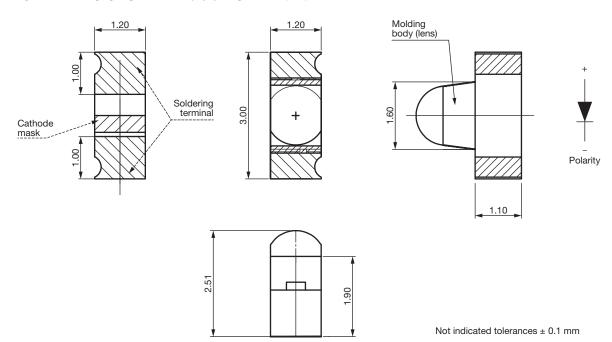
Moisture sensitivity level 3, according to J-STD-020.

DRYING

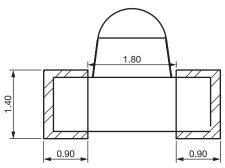
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 %.



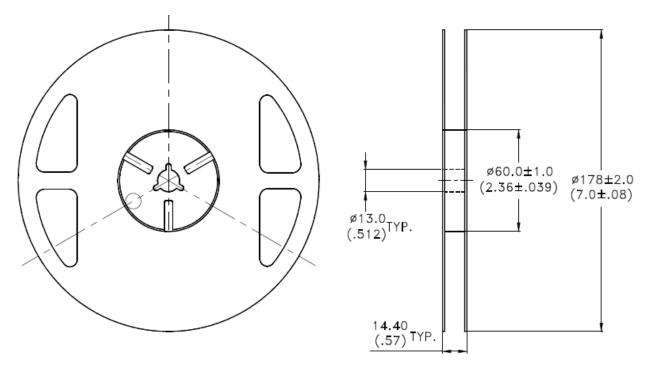
PACKAGE DIMENSIONS in millimeters: VSMY14940

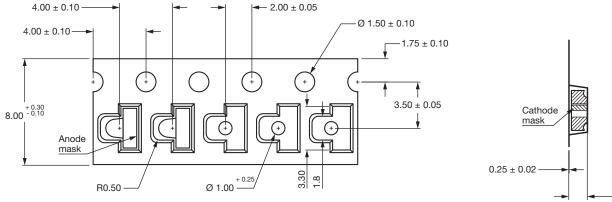


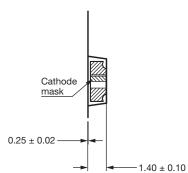
Recommended Solder Pad



TAPING AND REEL DIMENSIONS in millimeters: VSMY14940









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